

Tuesday 17 November

14:00

Strip Sensors Session | Location: CERN, TE Auditorium 14:00-14:20 First Results of SiBT test beam 2009 Speaker Jaakko Haerkoenen 14:20-14:40 Interstrip resistance in silicon position-sensitive detectors Speaker Dr Elena Verbitskaya 14:40-15:00 Charge collection annealing study of p-in-n silicon microstrip detectors Speaker Craig Wiglesworth 15:00-15:20 Annealing of Charge Collection Efficiency in highly irradiated MCz-n strip detectors. Speaker Mr Nicola Pacifico 15:20-15:40 Surface properties of ATLAS n-on-p sensors Speaker Hartmut Sadrozinski 15:40-16:10 Coffee break 16:10-16:30 Full-size ATLAS Sensor Testing (Late submission) Speaker Jan Bohm 16:30-16:50 Discussion on Strip Sensors (FDS) 16:50